## A New Tetrathiafulvalenium Complex with Copper Chloride: Electrical and Magnetic Properties

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High electrical powder conductivity (14 S cm<sup>-1</sup> at 300 K) and unusual temperature dependence were observed for a new tetrathiafulvalene (TTF) compound,  $[(TTF)_2]^+Cu^+Cl_2$ , which was prepared by oxidation of TTF with copper(II) chloride; the compound was characterized by e.s.r. and i.r. spectra as well as magnetic susceptibility.

Some 1,4,5,8-tetrathiafulvalene (TTF) salts have been found to exhibit high electrical conductivity which shows metal-like temperature dependence.<sup>1</sup> These 'molecular metals' were prepared by oxidation of TTF with oxidants such as  $Cl_2$ ,  $I_2$ , and 7,7,8,8-tetracyanoquinodimethane (TCNQ) or by electrochemical oxidation.<sup>1</sup> One of the features of the molecular metals is that the constituent molecules are in a mixed-valence (or intermediate oxidation) state; the formation of molecular metals requires appropriate conditions for oxidizing TTF. Extensive efforts have been made in the search for new ways to prepare a variety of molecular metals. This paper reports a new type of highly conducting TTF compound that can be prepared by using copper(II) chloride as an oxidant.

 $(TTF)_2CuCl_2$  was obtained as a dark purple powder by adding a methanol solution of  $CuCl_2 \cdot 2H_2O(0.1 \text{ mmol})$  to a methanol solution of TTF (0.22 mmol) under a nitrogen atmosphere.

The compressed pellets exhibited high electrical conductivity (14 S cm<sup>-1</sup> at 300 K), which showed unusual temperature dependence as shown in Figure 1. It is noteworthy that the powder conductivity is temperature-independent above *ca*. 250 K: the intrinsic conductivity may be metallic. Below *ca*. 160 K, the conductivity decreased rapidly with decreasing temperature: the material is semiconducting at lower temperatures, although the semilogarithmic plot of the conductivity *vs.* reciprocal temperature does not yield a straight line. This indicates the occurrence of a phase transition probably from a metallic state to a semiconducting state. This phase transition is reflected in the temperature dependence of the magnetic susceptibility (Figure 1): temperature-independent paramagnetism  $(3.3 \times 10^{-4} \text{ e.m.u. mol}^{-1} \text{ per compound formula})$ , which is characteristic of extensively delocalized spins, is displayed above *ca.* 220 K, and an abrupt change from



**Figure 1.** Temperature dependence of electrical powder conductivity,  $\sigma$ , and magnetic susceptibility,  $\chi$ , (per compound formula in e.m.u. mol<sup>-1</sup>) of (TTF)<sub>2</sub>CuCl<sub>2</sub>.

paramagnetism to diamagnetism takes place between 130 and 160 K.

The e.s.r. spectrum displayed a single symmetric signal with a g value of 2.0063, which is nearly equal to the value (2.00838) of TTF<sup>+</sup> in solution.<sup>2</sup> The paramagnetism arises from the organic radicals; the copper atoms are in the diamagnetic Cu<sup>I</sup> state. The i.r. spectrum exhibited a very broad band extending from 1000 to 4000 cm<sup>-1</sup>. Below the band edge, two peaks assignable to the  $b_{1u}$ -16 and  $b_{2u}$ -25 modes<sup>3</sup> of TTF appeared at 805 and 816 cm<sup>-1</sup>. These wavenumbers are intermediate betweeen those of TTF<sup>0</sup> and TTF<sup>+</sup>: the  $b_{1u}$ -16 mode appears at 781 and 836 cm<sup>-1</sup> for TTF<sup>0</sup> and TTF<sup>+</sup>, respectively, and the  $b_{2u}$ -25 mode at 794 and 825 cm<sup>-1</sup> for TTF<sup>0</sup> and TTF<sup>+</sup>, respectively.<sup>3</sup> This suggests a fractional-charge occupation of TTF. The formula can be written as  $[(TTF)_2]^+Cu^+Cl_2$  in which two TTF constituents share +1 charge.

When copper(II) bromide was used as an oxidant in place of the chloride, (TTF)<sub>5/3</sub>CuBr<sub>2</sub> was obtained under the same reaction conditions as mentioned above. The powder conductivity,  $\sigma$  (1.5 S cm<sup>-1</sup> at 297 K) followed  $\sigma = \sigma_{\infty} \exp(-E/kT)$ with E = 0.05 eV between 100 and 300 K. The magnetic susceptibility per compound formula was  $1.3 \times 10^{-4}$  and  $1.1 \times 10^{-4}$  e.m.u. mol<sup>-1</sup> at 297 and 114 K, respectively. The e.s.r. spectrum showed a single symmetric signal with g = 2.0065: TTF radicals are the paramagnetic species involved. A broad i.r. band assignable to  $b_{1u}$ -16 and/or  $b_{2u}$ -25 was observed at 825 cm<sup>-1</sup>.

The formation of the complexes accompanies the partial oxidation of TTF, shown in equation (1). Siedle, *et al.*<sup>4</sup> have

$$nTTF^{0} + Cu^{2+}X_{2} \rightarrow [(TTF)_{n}]^{+}Cu^{+}X_{2} \qquad (1)$$

reported that  $Cu^{2+}$  ions can oxidize  $TTF^0$  to  $TTF^+$  or  $TTF^{2+}$ ; the resulting salts were poorly conducting  $(10^{-2}-10^{-5} \text{ S cm}^{-1}$  at room temperature). The present study, however, demonstrates that under appropriate conditions,  $Cu^{II}$  compounds can function as excellent oxidants to form mixed-valence TTF compounds that are highly electroconductive. This together with our previous studies<sup>5</sup> of Cu-TCNQ complexes shows that the use of copper compounds as donors or acceptors may afford a versatile way to design various types of highly conducting materials.

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